Dual Channel Small Outline Optoisolator

Transistor Output

This device consists of two gallium arsenide infrared emitting diodes optically coupled to two monolithic silicon phototransistor detectors, in a surface mountable, small outline, plastic package. It is ideally suited for high density applications and eliminates the need for through–the–board mounting.

- Dual Channel Coupler
- Convenient Plastic SOIC-8 Surface Mountable Package Style
- Minimum Current Transfer Ratio 100% with Input Current of 10 mA
- Minimum V_{(BR)CEO} of 70 Volts Guaranteed
- Standard SOIC-8 Footprint, with 0.050" Lead Spacing
- · Shipped in Tape and Reel, which Conforms to EIA Standard RS481A
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input—Output Isolation of 3000 Vac (rms) Guaranteed
- Meets U.L. Regulatory Requirements, File #E54915

Ordering Information:

- To obtain MOCD213 in tape and reel, add R2 suffix to device number as follows:
 R2 = 2500 units on 13" reel
- To obtain MOCD213 in quantities of 50 (shipped in sleeves) no suffix

Marking Information:

MOCD213 = D213

Applications:

- Feedback Control Circuits
- Interfacing and Coupling Systems of Different Potentials and Impedances
- · General Purpose Switching Circuits
- · Monitor and Detection Circuits

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit			
INPUT LED						
Forward Current — Continuous	lF	60	mA			
Forward Current — Peak (PW = 100 μs, 120 pps)	IF(pk)	1.0	Α			
Reverse Voltage	٧R	6.0	V			
LED Power Dissipation @ T _A = 25°C Derate above 25°C	PD	90 0.8	mW mW/°C			
OUTPUT TRANSISTOR						

OUTPUT TRANSISTOR

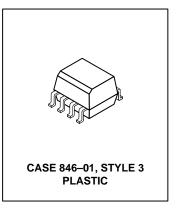
Collector–Emitter Voltage	VCEO	70	V
Collector–Base Voltage	VCBO	70	V
Emitter–Collector Voltage	VECO	7.0	V
Collector Current — Continuous	IC	150	mA
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	150 1.76	mW mW/°C

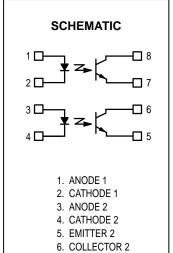
NOTE: Thickness through insulation between input and output is $\geq 0.5 \ \text{mm}.$

MOCD213

[CTR = 100% Min]

DUAL CHANNEL SMALL OUTLINE OPTOISOLATOR TRANSISTOR OUTPUT





7. EMITTER 1 8. COLLECTOR 1 **TOTAL DEVICE**

MAXIMUM RATINGS—continued ($T_A = 25^{\circ}C$ unless otherwise noted)

Rating

Input–Output Isolation Voltage(1,2) (60 Hz, 1.0 sec. duration)		VISO	30	000	Vac(rms)	
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C		PD	_	50 .94	mW mW/°C	
Ambient Operating Temperature Range ⁽³⁾ Storage Temperature Range ⁽³⁾		TA	-55 to +100		°C	
		T _{stg}	-55 to	-55 to +150		
Lead Soldering Temperature (1/16" from case, 10 sec. duration)			2	60	°C	
ELECTRICAL CHARACTERIS	TICS (T _A = 25°C unless otherwise	e noted)(4)				
Charact	eristic	Symbol	Min	Typ ⁽⁴⁾	Max	Unit
INPUT LED		•			•	
Forward Voltage (IF = 30 mA)		VF	_	1.2	1.55	V
Reverse Leakage Current (V _R = 6	Reverse Leakage Current (V _R = 6.0 V)		_	0.1	100	μΑ
Capacitance		С	_	18	_	pF
OUTPUT TRANSISTOR						
Collector–Emitter Dark Current	$(V_{CE} = 10 \text{ V}, T_{A} = 25^{\circ}\text{C})$	ICEO1	_	1.0	50	nA
	$(V_{CE} = 10 \text{ V}, T_{A} = 100^{\circ}\text{C})$	ICEO2	_	1.0	_	μΑ
Collector–Emitter Breakdown Voltage (I _C = 100 μA)		V(BR)CEO	70	120	_	V
Emitter–Collector Breakdown Voltage (I _E = 100 μA)		V(BR)ECO	7.0	7.8	_	V
Collector–Emitter Capacitance (f = 1.0 MHz, V _{CE} = 0)		C _{CE}	_	7.0	_	pF
COUPLED						
Output Collector Current (I _F = 10 mA, V _{CE} = 5 V)	MOCD213	I _C (CTR) ⁽⁵⁾	10 (100)	_	_	mA (%)
Collector-Emitter Saturation Volta	ge (I _C = 2.0 mA, I _F = 10 mA)	VCE(sat)	_	0.15	0.4	V
Turn-On Time (I _C = 2.0 mA, V_{CC} = 10 V, R_L = 100 Ω)		t _{on}	_	3.0	_	μs
Turn–Off Time (I _C = 2.0 mA, V_{CC} = 10 V, R_L = 100 Ω)		t _{off}	_	2.8	_	μs
Rise Time (I_C = 2.0 mA, V_{CC} = 10 V, R_L = 100 Ω)		t _r	_	1.6	_	μs
Fall Time (I _C = 2.0 mA, V_{CC} = 10 V, R_L = 100 Ω)		t _f		2.2		μs
Input-Output Isolation Voltage (f = 60 Hz, t = 1.0 sec)(1,2)		Viso	3000	_	_	Vac(rms)
Isolation Resistance (V _{I-O} = 500 V)(2)		R _{ISO}	10 ¹¹	_	_	Ω
	(a)					

CISO

- 1. Input–Output Isolation Voltage, $V_{\mbox{\scriptsize ISO}}$, is an internal device dielectric breakdown rating.
- 2. For this test, pins 1, 2, 3, and 4 are common, and pins 5, 6, 7 and 8 are common.
- 3. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.
- 4. Always design to the specified minimum/maximum electrical limits (where applicable).
- 5. Current Transfer Ratio (CTR) = I_C/I_F x 100%.

Isolation Capacitance $(V_{I-O} = 0, f = 1.0 \text{ MHz})(2)$

0.2

Value

Symbol

Unit

рF

TYPICAL CHARACTERISTICS

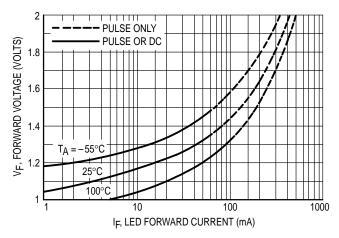


Figure 1. LED Forward Voltage versus Forward Current

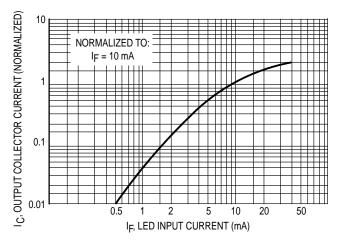


Figure 2. Output Current versus Input Current

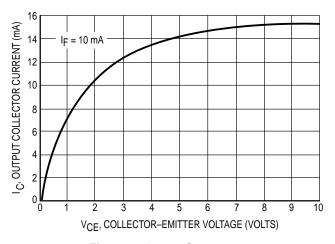


Figure 3. Output Current versus Collector–Emitter Voltage

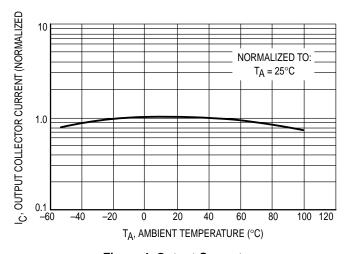


Figure 4. Output Current versus
Ambient Temperature

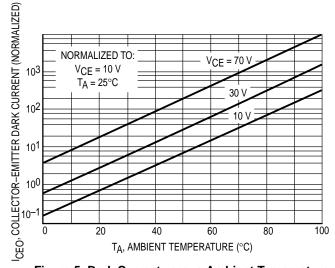


Figure 5. Dark Current versus Ambient Temperature

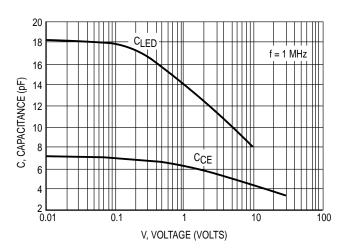
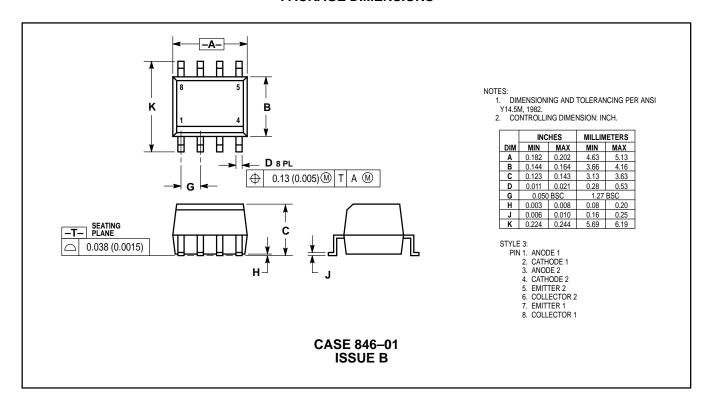


Figure 6. Capacitance versus Voltage

PACKAGE DIMENSIONS



Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and ** are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us:

USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912: Phoenix. Arizona 85036. 1–800–441–2447

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244–6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, Toshikatsu Otsuki, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–3521–8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298





www.s-manuals.com